

# PS2705A-1

R08DS0073EJ0502

Rev.5.02

HIGH ISOLATION VOLTAGE SOP PHOTOCOUPLER

May 14, 2020

## DESCRIPTION

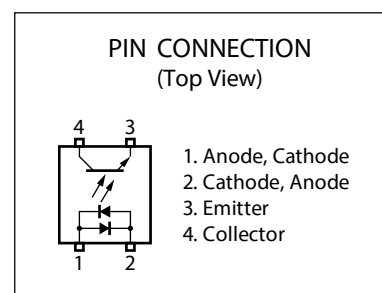
The PS2705A-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon phototransistor to realize an excellent cost performance.

This package is SOP (Small Outline Package) type and has shield effect to cut off ambient light.

It is designed for high density mounting applications.

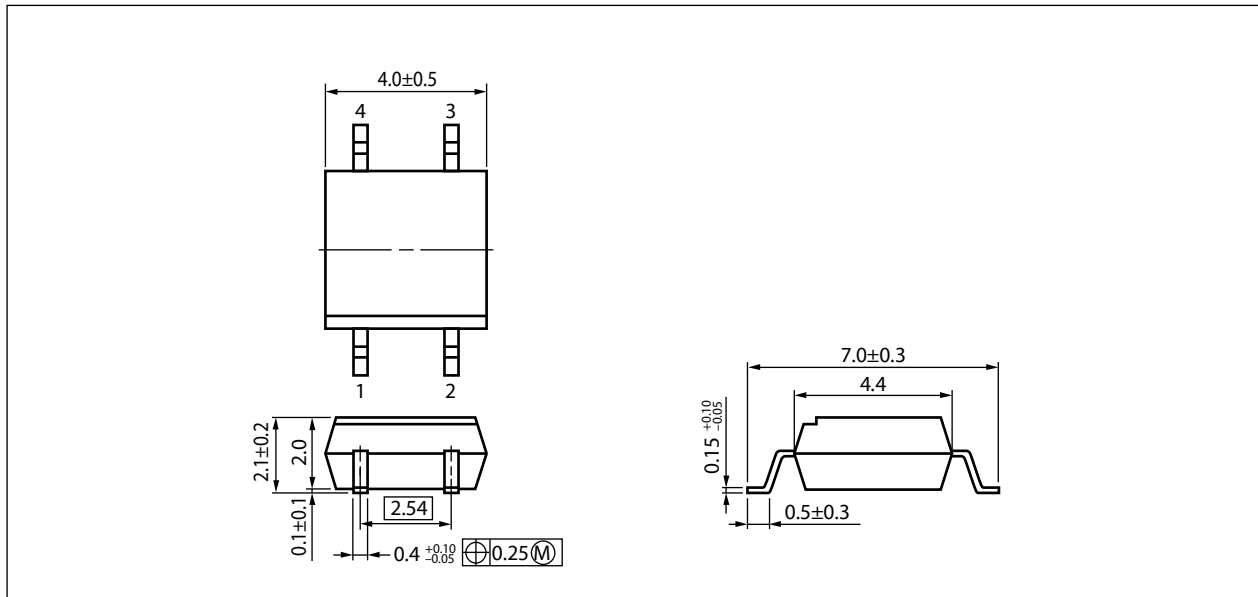
## FEATURES

- AC input response
- High isolation voltage (BV = 3 750 Vr.m.s.)
- SOP (Small Outline Package) type
- Ordering number of taping product: PS2705A-1-F3: 3 500 pcs/reel
- Pb-Free product
- Safety standards
  - UL approved: UL1577, Single protection
  - CSA approved: CAN/CSA-C22.2 No. 62368-1, Basic/Supplementary insulation
  - SEMKO approved: EN 62368-1, IEC 62368-1, Basic/Supplementary insulation
  - NEMKO approved: EN 62368-1, Basic/Supplementary insulation
  - FIMKO approved: EN 62368-1, Basic/Supplementary insulation
  - DEMKO approved: EN 62368-1, Basic/Supplementary insulation
  - VDE approved: DIN EN 60747-5-5 (Option)



## APPLICATIONS

- Hybrid IC
- Telephone/FAX.
- FA/OA equipment
- Programmable logic controllers
- Power supply

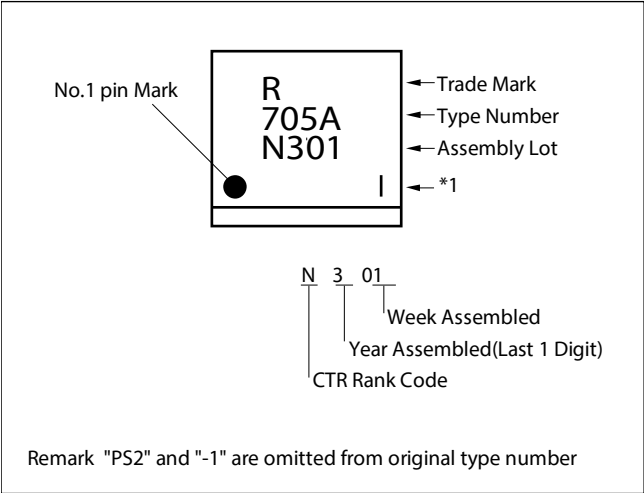
**PACKAGE DIMENSIONS (UNIT: mm)**

Weight : 0.08 g (typ.)

**PHOTOCOUPLER CONSTRUCTION**

| Parameter          | Unit (MIN.) |
|--------------------|-------------|
| Air Distance       | 5 mm        |
| Creepage Distance  | 5 mm        |
| Isolation Distance | 0.3 mm      |

MARKING EXAMPLE



Note: Bar indication contents of \*1.

|                                                      |                                                                                                                                                                                                      |
|------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>Made in Taiwan</b><br>( *1: No indication )       | <p>The marking area shows 'R', '705A', 'N301', and a dot in the bottom-left corner. There is no vertical bar.</p>                                                                                    |
| <b>Made in Japan</b><br>( *1: "   " (Vertical bar) ) | <p>The marking area shows 'R', '705A', 'N301', a dot in the bottom-left corner, and a vertical bar ' '. An arrow points from the text '"   " (Vertical bar) :Made in Japan' to the vertical bar.</p> |

## ORDERING INFORMATION

| Part Number    | Order Number <sup>*1</sup> | Solder Plating Specification | Packing Style                   | Safety Standard Approval                                                  | Application Part Number <sup>*2</sup> |
|----------------|----------------------------|------------------------------|---------------------------------|---------------------------------------------------------------------------|---------------------------------------|
| PS2705A-1      | PS2705A-1-A                | Pb-Free                      | 20 pcs<br>(Tape 20 pcs cut)     | Standard products<br>(UL, CSA, SEMKO,<br>NEMKO, FIMKO,<br>DEMKO approved) | PS2705A-1                             |
| PS2705A-1-F3   | PS2705A-1-F3-A             |                              | Embossed Tape<br>3 500 pcs/reel |                                                                           |                                       |
| PS2705A-1-V    | PS2705A-1-V-A              |                              | 20 pcs<br>(Tape 20 pcs cut)     | UL, CSA, SEMKO,<br>NEMKO, FIMKO,                                          |                                       |
| PS2705A-1-V-F3 | PS2705A-1-V-F3-A           |                              | Embossed Tape<br>3 500 pcs/reel | DIN EN 60747-5-5<br>approved                                              |                                       |

Notes: \*1. When specifying CTR rank, please add "/CTR rank" after Order Number.

ex. L rank : PS2705A-1-A/L

Notes: \*2. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ , unless otherwise specified)

| Parameter                       |                                    | Symbol                      | Ratings     | Unit                 |
|---------------------------------|------------------------------------|-----------------------------|-------------|----------------------|
| Diode                           | Forward Current (DC)               | $I_F$                       | $\pm 50$    | mA                   |
|                                 | Power Dissipation Derating         | $\Delta P_D/^\circ\text{C}$ | 0.8         | mW/ $^\circ\text{C}$ |
|                                 | Power Dissipation                  | $P_D$                       | 80          | mW                   |
|                                 | Peak Forward Current <sup>*1</sup> | $I_{FP}$                    | $\pm 0.5$   | A                    |
| Transistor                      | Collector to Emitter Voltage       | $V_{CEO}$                   | 70          | V                    |
|                                 | Emitter to Collector Voltage       | $V_{ECO}$                   | 5           | V                    |
|                                 | Collector Current                  | $I_C$                       | 30          | mA                   |
|                                 | Power Dissipation Derating         | $\Delta P_C/^\circ\text{C}$ | 1.5         | mW/ $^\circ\text{C}$ |
|                                 | Power Dissipation                  | $P_C$                       | 150         | mW                   |
| Isolation Voltage <sup>*2</sup> |                                    | BV                          | 3 750       | Vr.m.s.              |
| Operating Ambient Temperature   |                                    | $T_A$                       | -55 to +100 | $^\circ\text{C}$     |
| Storage Temperature             |                                    | $T_{stg}$                   | -55 to +150 | $^\circ\text{C}$     |

Note: \*1. PW = 100  $\mu\text{s}$ , Duty Cycle = 1%

\*2. AC voltage for 1 minute at  $T_A = 25^\circ\text{C}$ , RH = 60% between input and output.

Pins 1-2 shorted together, 3-4 shorted together.

**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)**

|            | Parameter                                                              | Symbol               | Conditions                                                           | MIN.             | TYP. | MAX. | Unit |
|------------|------------------------------------------------------------------------|----------------------|----------------------------------------------------------------------|------------------|------|------|------|
| Diode      | Forward Voltage                                                        | V <sub>F</sub>       | I <sub>F</sub> = ±5 mA                                               |                  | 1.2  | 1.4  | V    |
|            | Terminal Capacitance                                                   | C <sub>t</sub>       | V = 0 V, f = 1.0 MHz                                                 |                  | 20   |      | pF   |
| Transistor | Collector to Emitter Dark Current                                      | I <sub>CEO</sub>     | I <sub>F</sub> = 0 mA, V <sub>CE</sub> = 70 V                        |                  |      | 100  | nA   |
| Coupled    | Current Transfer Ratio (I <sub>C</sub> /I <sub>F</sub> ) <sup>*1</sup> | CTR                  | I <sub>F</sub> = ±5 mA, V <sub>CE</sub> = 5 V                        | 50               |      | 300  | %    |
|            | Collector Saturation Voltage                                           | V <sub>CE(sat)</sub> | I <sub>F</sub> = ±10 mA, I <sub>C</sub> = 2 mA                       |                  | 0.13 | 0.3  | V    |
|            | Isolation Resistance                                                   | R <sub>I-O</sub>     | V <sub>I-O</sub> = 1.0 kV <sub>DC</sub>                              | 10 <sup>11</sup> |      |      | Ω    |
|            | Isolation Capacitance                                                  | C <sub>I-O</sub>     | V = 0 V, f = 1.0 MHz                                                 |                  | 0.4  |      | pF   |
|            | Rise Time <sup>*2</sup>                                                | t <sub>r</sub>       | V <sub>CC</sub> = 5 V, I <sub>C</sub> = 2 mA, R <sub>L</sub> = 100 Ω |                  | 5    |      | μs   |
|            | Fall Time <sup>*2</sup>                                                | t <sub>f</sub>       |                                                                      |                  | 7    |      |      |
|            | Turn-on Time <sup>*2</sup>                                             | t <sub>on</sub>      |                                                                      |                  | 8    |      |      |
|            | Turn-off Time <sup>*2</sup>                                            | t <sub>off</sub>     |                                                                      |                  | 10   |      |      |

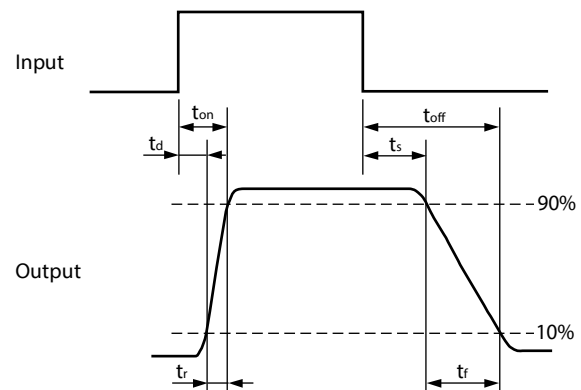
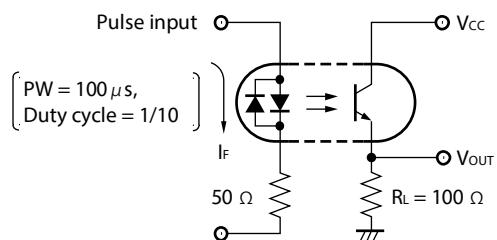
Note: \*1. CTR rank

N: 50 to 300 (%)

L: 100 to 300 (%)

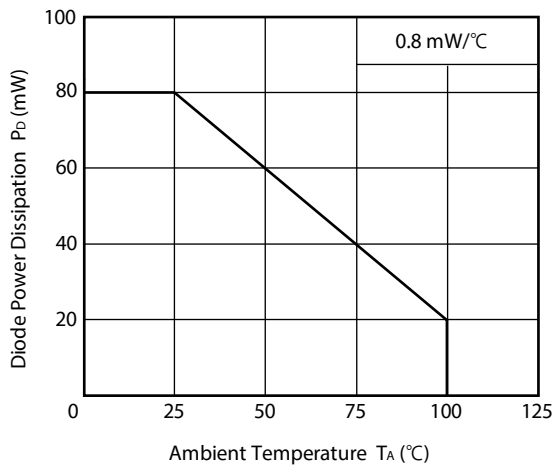
M: 50 to 150 (%)

\*2. Test Circuit for Switching Time

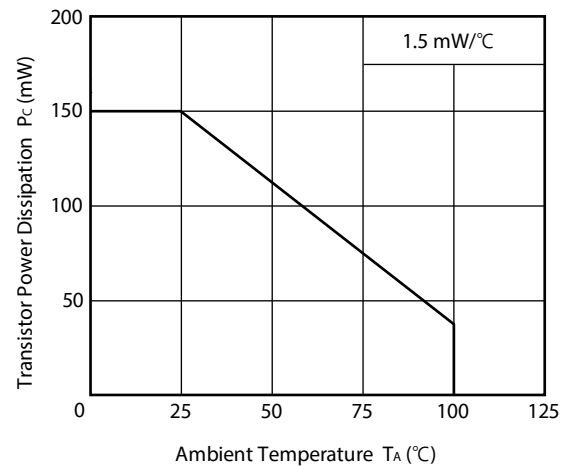


# TYPICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ , unless otherwise specified)

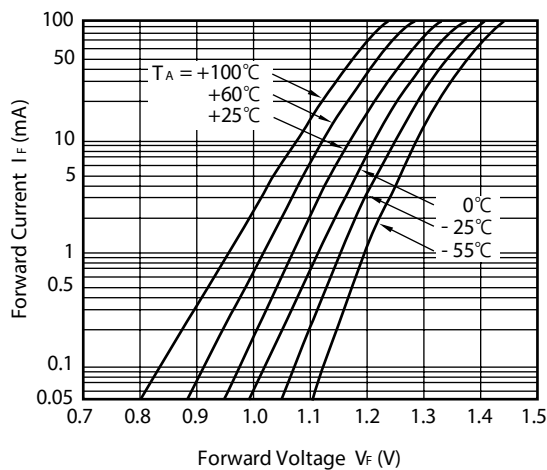
DIODE POWER DISSIPATION vs.  
AMBIENT TEMPERATURE



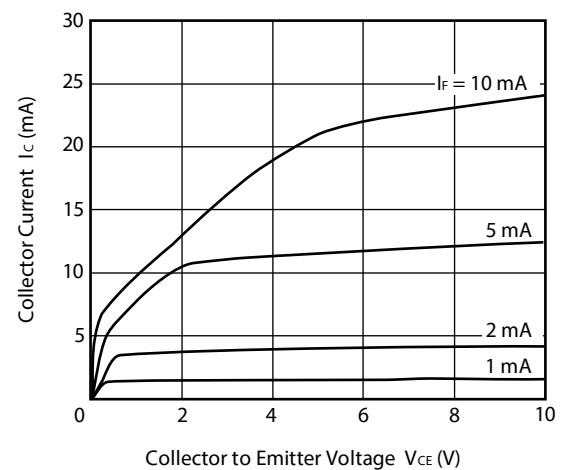
TRANSISTOR POWER DISSIPATION vs.  
AMBIENT TEMPERATURE



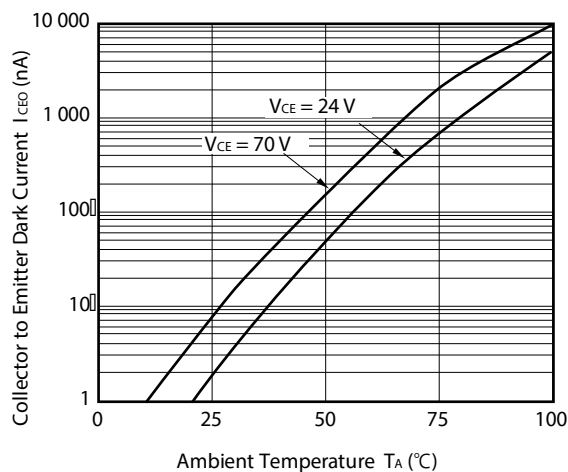
FORWARD CURRENT vs.  
FORWARD VOLTAGE



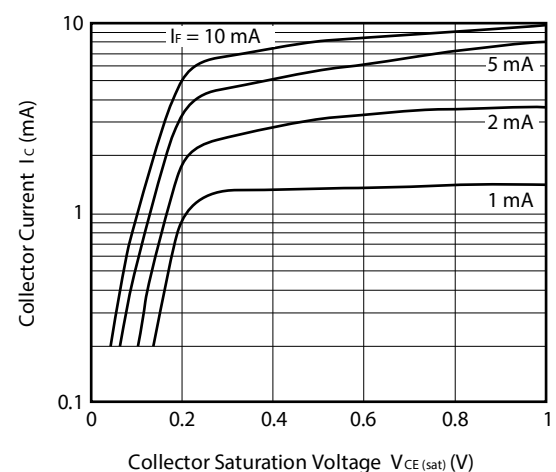
COLLECTOR CURRENT vs.  
COLLECTOR TO EMITTER VOLTAGE



COLLECTOR TO EMITTER DARK  
CURRENT vs. AMBIENT TEMPERATURE

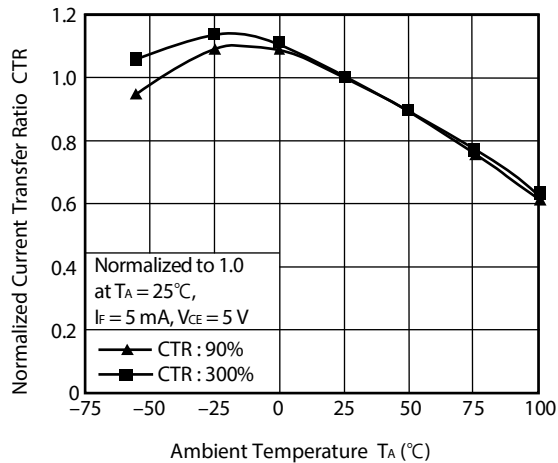


COLLECTOR CURRENT vs.  
COLLECTOR SATURATION VOLTAGE

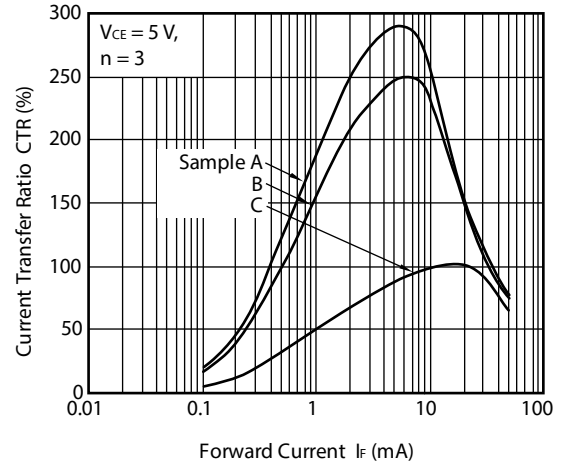


**Remark** The graphs indicate nominal characteristics.

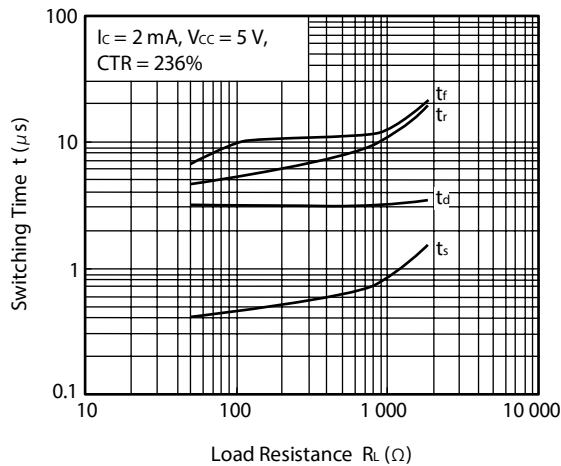
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



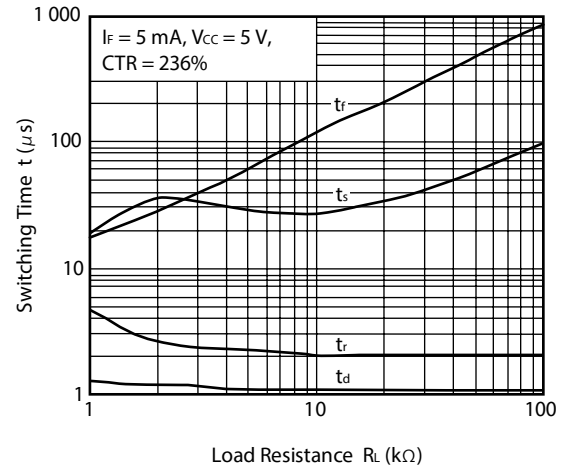
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



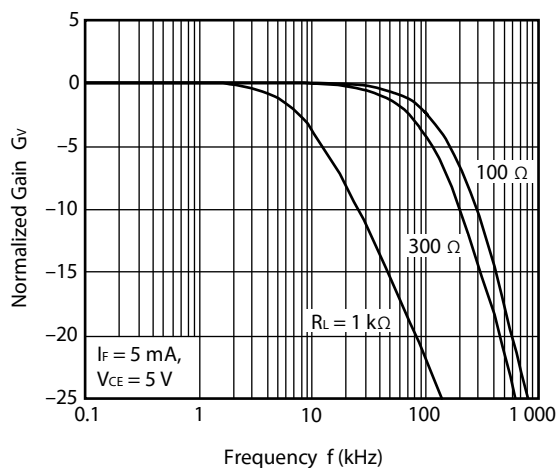
SWITCHING TIME vs. LOAD RESISTANCE



SWITCHING TIME vs. LOAD RESISTANCE



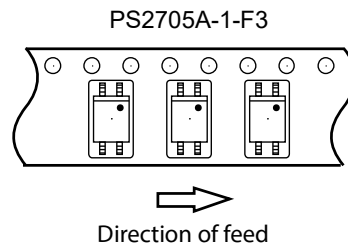
FREQUENCY RESPONSE



**Remark** The graphs indicate nominal characteristics.

## TAPING SPECIFICATIONS (UNIT: mm)

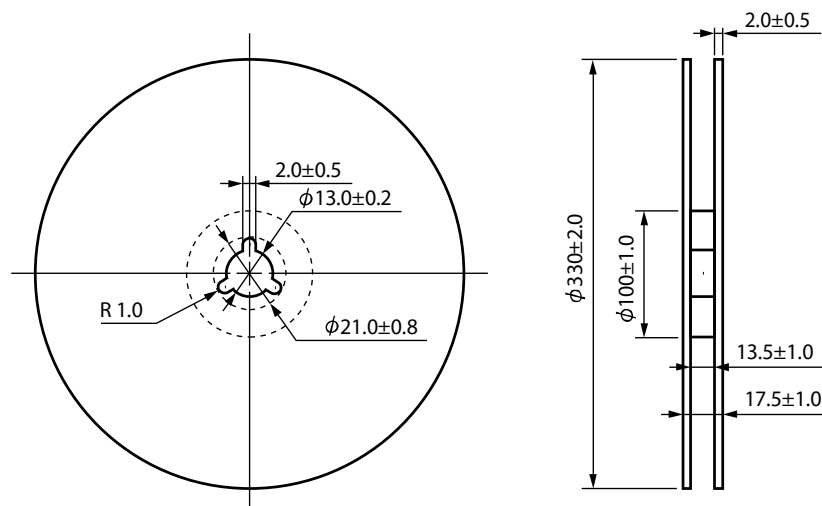
Tape Direction



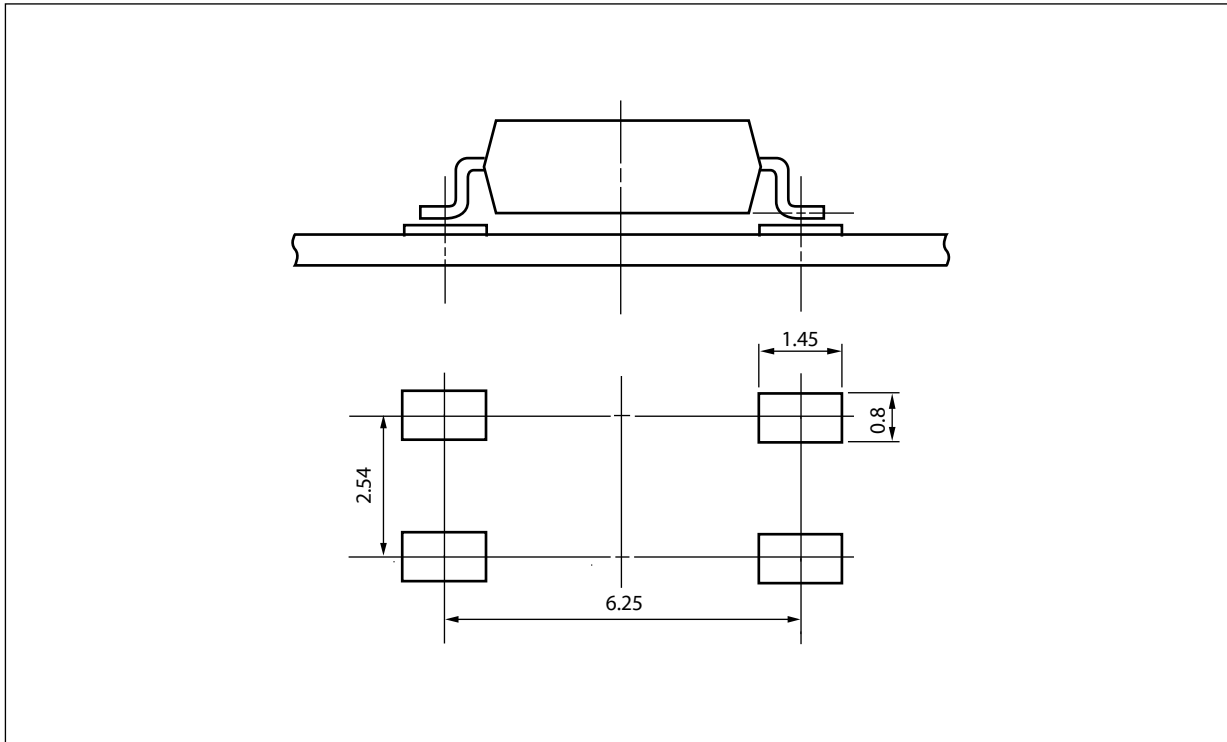
Outline and Dimensions (Tape)



Outline and Dimensions (Reel)



Packing: 3 500 pcs/reel

**RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)**

**Remark** All dimensions in this figure must be evaluated before use.

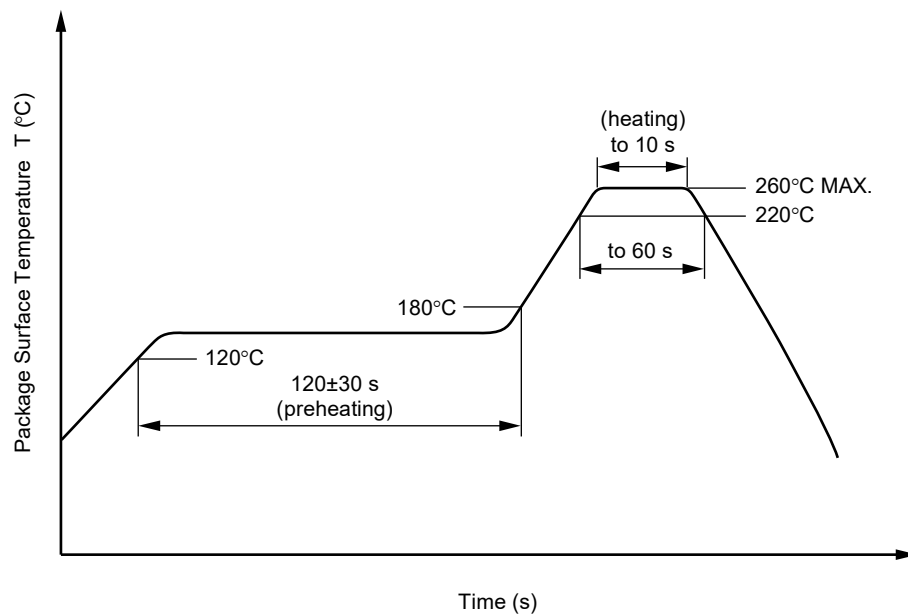
## NOTES ON HANDLING

### 1. Recommended soldering conditions

#### (1) Infrared reflow soldering

- |                                                 |                                                                                                                         |
|-------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------|
| • Peak reflow temperature                       | 260°C or below (package surface temperature)                                                                            |
| • Time of peak reflow temperature               | 10 seconds or less                                                                                                      |
| • Time of temperature higher than 220°C         | 60 seconds or less                                                                                                      |
| • Time to preheat temperature from 120 to 180°C | 120±30 s                                                                                                                |
| • Number of reflows                             | Three                                                                                                                   |
| • Flux                                          | Rosin flux containing small amount of chlorine<br>(The flux with a maximum chlorine content of 0.2 Wt% is recommended.) |

Recommended Temperature Profile of Infrared Reflow



#### (2) Wave soldering

- |                         |                                                                                                                      |
|-------------------------|----------------------------------------------------------------------------------------------------------------------|
| • Temperature           | 260°C or below (molten solder temperature)                                                                           |
| • Time                  | 10 seconds or less                                                                                                   |
| • Preheating conditions | 120°C or below (package surface temperature)                                                                         |
| • Number of times       | One (Allowed to be dipped in solder including plastic mold portion.)                                                 |
| • Flux                  | Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.) |

#### (3) Soldering by Soldering Iron

- |                                            |                                                                                                                         |
|--------------------------------------------|-------------------------------------------------------------------------------------------------------------------------|
| • Peak Temperature (lead part temperature) | 350°C or below                                                                                                          |
| • Time (each pins)                         | 3 seconds or less                                                                                                       |
| • Flux                                     | Rosin flux containing small amount of chlorine<br>(The flux with a maximum chlorine content of 0.2 Wt% is recommended.) |

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(b) Please be sure that the temperature of the package would not be heated over 100°C

#### (4) Cautions

- Flux Cleaning  
Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.
- Do not use fixing agents or coatings containing halogen-based substances.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler

Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. This tendency may sometimes be obvious, especially below  $I_F = 1 \text{ mA}$ .

Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

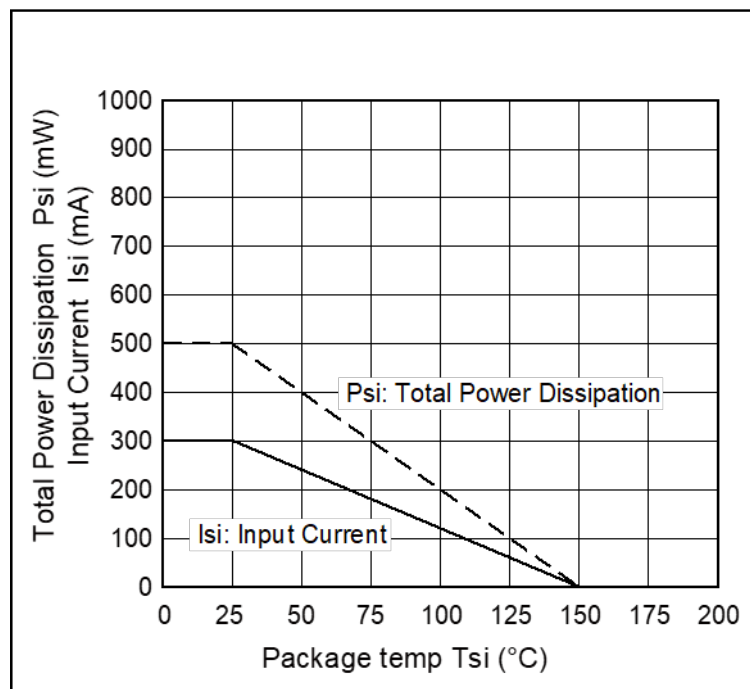
## USAGE CAUTIONS

1. Protect against static electricity when handling.
2. Avoid storage at a high temperature and high humidity.
3. Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.
4. Do not use fixing agents or coatings containing halogen-based substances.

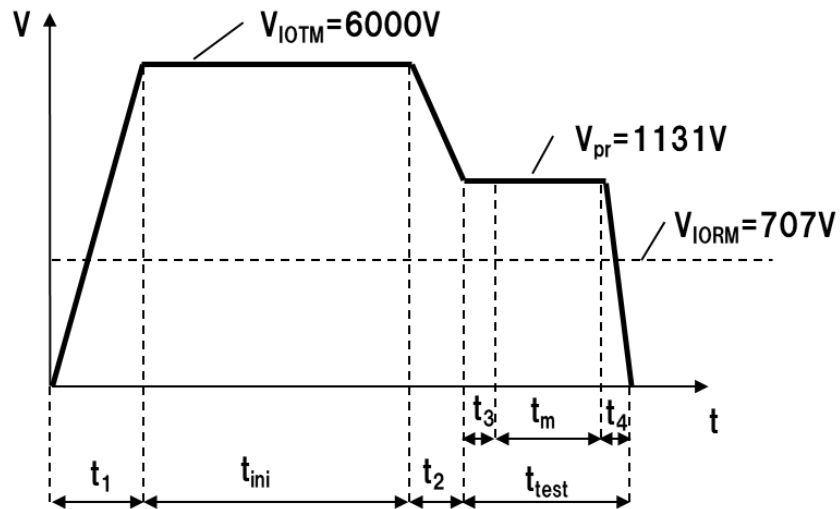
## SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

| Parameter                                                                                 | Symbol     | Rating      | Unit       |
|-------------------------------------------------------------------------------------------|------------|-------------|------------|
| Climatic test class (IEC 60068-1/DIN EN 60068-1)                                          |            | 55/100/21   |            |
| Dielectric strength                                                                       |            |             |            |
| maximum operating isolation voltage                                                       | $U_{IORM}$ | 707         | $V_{peak}$ |
| Test voltage (partial discharge test, procedure a for type test and random test)          | $U_{pr}$   | 1 131       | $V_{peak}$ |
| $U_{pr} = 1.6 \times U_{IORM}$ , $P_d < 5 \text{ pC}$                                     |            |             |            |
| Test voltage (partial discharge test, procedure b for all devices)                        | $U_{pr}$   | 1 325       | $V_{peak}$ |
| $U_{pr} = 1.875 \times U_{IORM}$ , $P_d < 5 \text{ pC}$                                   |            |             |            |
| Highest permissible overvoltage                                                           | $U_{IOTM}$ | 6 000       | $V_{peak}$ |
| Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))                             |            | 2           |            |
| Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11))                         | CTI        | 175         |            |
| Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))                                  |            | III a       |            |
| Storage temperature range                                                                 | $T_{stg}$  | -55 to +150 | °C         |
| Operating temperature range                                                               | $T_A$      | -55 to +100 | °C         |
| Isolation resistance, minimum value                                                       |            |             |            |
| $V_{IO} = 500 \text{ V dc}$ at $T_A = 25^\circ\text{C}$                                   | Ris MIN.   | $10^{12}$   | $\Omega$   |
| $V_{IO} = 500 \text{ V dc}$ at $T_A \text{ MAX.}$ at least $100^\circ\text{C}$            | Ris MIN.   | $10^{11}$   | $\Omega$   |
| Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) |            |             |            |
| Package temperature                                                                       | $T_{si}$   | 150         | °C         |
| Current (input current $I_F$ , $\Psi_i = 0$ )                                             | $I_{si}$   | 300         | mA         |
| Power (output or total power dissipation)                                                 | $\Psi_i$   | 500         | mW         |
| Isolation resistance                                                                      |            |             |            |
| $V_{IO} = 500 \text{ V dc}$ at $T_A = T_{si}$                                             | Ris MIN.   | $10^9$      | $\Omega$   |

## Dependence of maximum safety ratings with package temperature



### Method a) Destructive Test, Type and Sample Test



$t_1, t_2 = 1 \text{ to } 10 \text{ sec}$

$t_3, t_4 = 1 \text{ sec}$

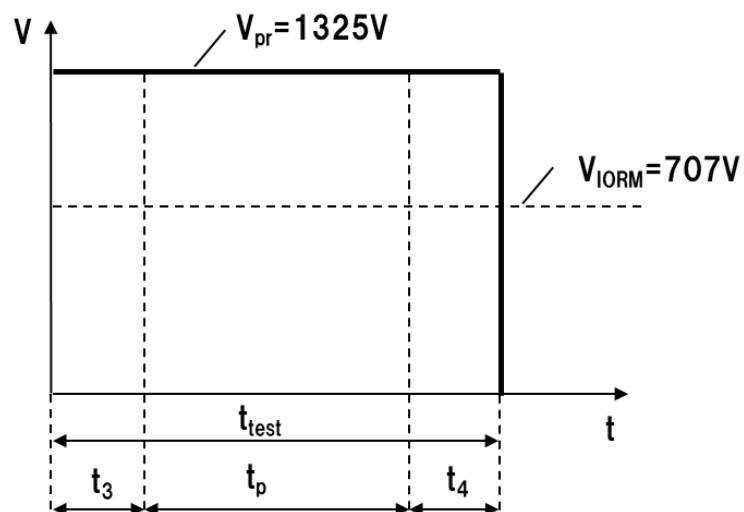
$t_m \text{ (PARTIAL DISCHARGE)} = 10 \text{ sec}$

$t_{test} = 12 \text{ sec}$

$t_{ini} = 60 \text{ sec}$

### Method b) Non-destructive Test, 100% Production Test

<R>



$t_3, t_4 = 0.1 \text{ sec}$

$t_p \text{ (PARTIAL DISCHARGE)} = 1.0 \text{ sec}$

$t_{test} = 1.2 \text{ sec}$

**Caution**

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
  1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
  2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

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(Rev.4.0-1 November 2017)



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TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan

**Renesas Electronics America Inc.**  
1001 Murphy Ranch Road, Milpitas, CA 95035, U.S.A.  
Tel: +1-408-432-8888, Fax: +1-408-434-5351

**Renesas Electronics Canada Limited**  
9251 Yonge Street, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3  
Tel: +1-905-237-2004

**Renesas Electronics Europe GmbH**  
Arcadiastrasse 10, 40472 Düsseldorf, Germany  
Tel: +49-211-6503-0, Fax: +49-211-6503-1327

**Renesas Electronics (China) Co., Ltd.**  
Room 101-T01, Floor 1, Building 7, Yard No. 7, 8th Street, Shangdi, Haidian District, Beijing 100085, China  
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

**Renesas Electronics (Shanghai) Co., Ltd.**  
Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai 200333, China  
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

**Renesas Electronics Hong Kong Limited**  
Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong  
Tel: +852-2265-6688, Fax: +852 2886-9022

**Renesas Electronics Taiwan Co., Ltd.**  
13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan  
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

**Renesas Electronics Singapore Pte. Ltd.**  
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre, Singapore 339949  
Tel: +65-6213-0200, Fax: +65-6213-0300

**Renesas Electronics Malaysia Sdn.Bhd.**  
Unit No 3A-1 Level 3A Tower 8 UOA Business Park, No 1 Jalan Pengaturcara U1/51A, Seksyen U1, 40150 Shah Alam, Selangor, Malaysia  
Tel: +60-3-5022-1288, Fax: +60-3-5022-1290

**Renesas Electronics India Pvt. Ltd.**  
No.777C, 100 Feet Road, HAL 2nd Stage, Indiranagar, Bangalore 560 038, India  
Tel: +91-80-67208700

**Renesas Electronics Korea Co., Ltd.**  
17F, KAMCO Yangjae Tower, 262, Gangnam-daero, Gangnam-gu, Seoul, 06265 Korea  
Tel: +82-2-558-3737, Fax: +82-2-558-5338